FAIRCHILD

SEMICONDUCTOR®

FDH5500_F085

N-Channel UltraFET Power MOSFET

55V, 75A, 7m Ω

Features

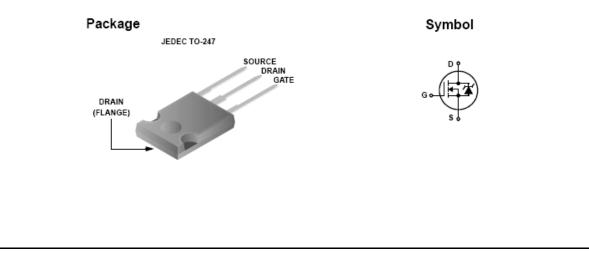
- Typ r_{DS(on)} = 5.2mΩ at V_{GS} = 10V, I_D = 75A
- Typ Q_{g(10)} = 118nC at V_{GS} = 10V
- Simulation Models
 -Temperature Compensated PSPICE and SABERTM Models
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Related Literature
 - -TB334, "Guidelines for Soldering Surface Mount Componets to PC Boards"
- Qualified to AEC Q101
- RoHS Compliant

Applications

- DC Linear Mode Control
- Solenoid and Motor Control
- Switching Regulators
- Automotive Systems

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Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage	(Note 1)	55	V
V _{DGR}	Drain to Gate Voltage (R_{GS} = 20k Ω)	(Note 1)	55	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (T _C < 135 ^o C, V _{GS} = 10V)			Α
D	Pulsed		See Figure 4	A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	864	mJ
	Power Dissipation		375	W
P _D	Dreate above 25°C		2.5	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	
ΤL	Max. Lead Temp. for Soldering (at 1.6mm from case for 10sec)		300	°C
T _{pkq}	Max. Package Temp. for Soldering (Package Body for 10sec)		260	

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case	0.4	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient TO-247, 1in ² copper pad area	30	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDH5500	FDH5500_F085	TO-247	Tube	N/A	30 units

Electrical Characteristics T_{C} = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

Off Characteristics

B_{VDSS}	Drain to Source Breakdown Voltage	$I_{\rm D}$ = 250 μ A, V _{GS} = 0	$I_{D} = 250 \mu A, V_{GS} = 0V$		-	-	V
1	Zero Gate Voltage Drain Current	V_{DS} = 50V, V_{GS} = 0	IV .	-	-	1	
DSS	Zero Gale volage Drain Current	V _{DS} = 45V	T _C = 150 ^o C	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	2.9	4	V
r _{DS(on)}	Drain to Source On Resistance	I _D = 75A, V _{GS} = 10V	-	5.2	7	mΩ

Dynamic Characteristics

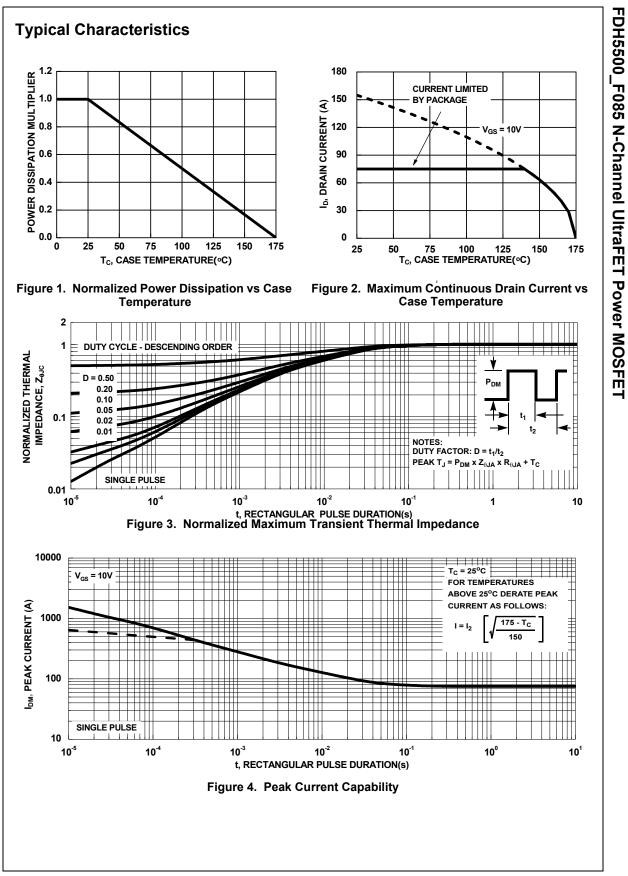
C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	3565	-	pF
C _{oss}	Output Capacitance			-	1310	-	pF
C _{rss}	Reverse Transfer Capacitance			-	395	-	pF
Q _{g(TOT)}	Total Gate Charge at 20V	V _{GS} = 0 to 20V		-	206	268	nC
Q _{g(10)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V	$V_{DD} = 30V$	-	118	153	nC
Q _{g(TH)}	Threshold Gate Charge	V_{GS} = 0 to 2V	I _D = 75A R ₁ = 0.4Ω	-	6.2	8.1	nC
Q _{gs}	Gate to Source Gate Charge		$I_{a} = 1.0 \text{mA}$	-	17.8	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		y -	-	51	-	nC

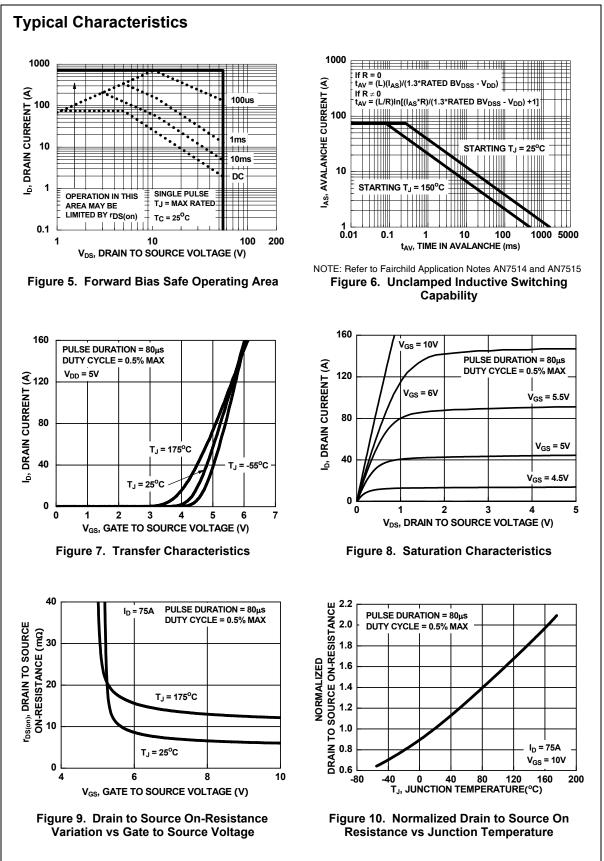
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
on	Turn-On Time		-	-	185	ns
d(on)	Turn-On Delay Time		-	13.7	-	ns
r r	Rise Time	$ \begin{array}{c} \hline & \\ V_{DD} = 30V, \ I_{D} = 75A, \\ \hline & \\ R_{L} = 0.4\Omega, \ V_{GS} = 10V, \\ \hline & \\ R_{GS} = 2.5\Omega \end{array} $	-	102	-	ns
d(off)	Turn-Off Delay Time		-	34	-	ns
l _f	Fall Time		-	22	-	ns
off	Turn-Off Time		-	-	91	ns
Drain-So	Source Diode Characteristics	I _{SD} = 75A	-	1	1.25	V
t _{rr}	Reverse Recovery Time	I _F = 75A, dI _{SD} /dt = 100A/μs	-	60	78	ns
Q _{rr}	Reverse Recovery Charge	$_{\rm F}$ = 75A, $\rm di_{SD}/\rm dt$ = 100A/µS	-	77	100	nC

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

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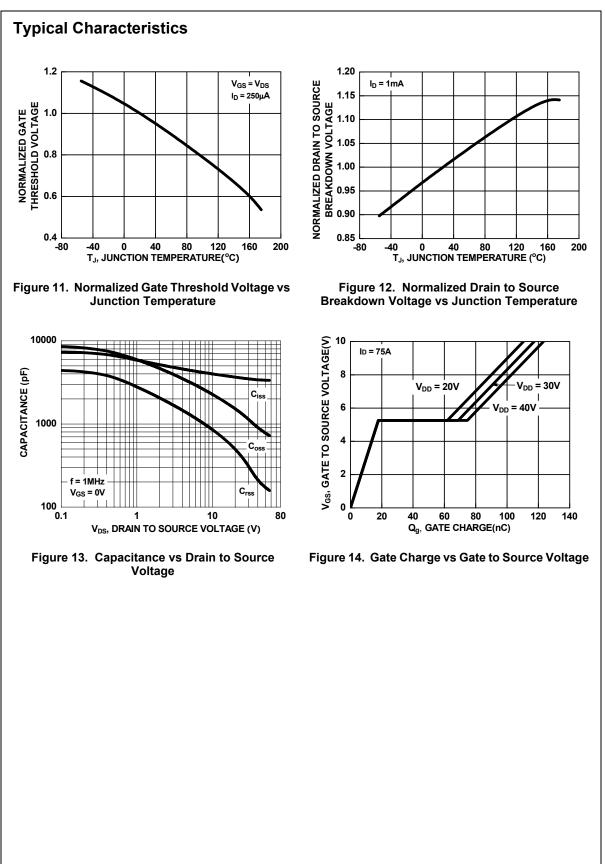




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